

Bin Amin

List of Publications by Year in Descending Order

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The third column is the impact factor (IF) of the journal, and the fourth column is the number of citations of the article.

75
papers

2,059
citations

24
h-index

44
g-index

80
ext. papers

2,623
ext. citations

3.2
avg, IF

5.45
L-index

#	Paper	IF	Citations
75	Strain effect on the electronic and photocatalytic properties of GaN-MSSe (M=Mo, W). <i>Journal of Solid State Chemistry</i> , 2022 , 306, 122798	3.3	0
74	Van der Waal heterostructure of hBAs and XMY (M = Mo, W; (XY) = S, Se) monolayers. <i>Chemical Physics</i> , 2022 , 552, 111374	2.3	0
73	First principles study of optoelectronic and photocatalytic performance of novel transition metal dipnictide XP (X = Ti, Zr, Hf) monolayers.. <i>RSC Advances</i> , 2022 , 12, 11202-11206	3.7	0
72	Intriguing interfacial characteristics of the CS contact with MX (M = Mo, W; X = S, Se, Te) and MXY ((XY) = S, Se, Te) monolayers.. <i>RSC Advances</i> , 2022 , 12, 12292-12302	3.7	0
71	Intriguing electronic, optical and photocatalytic performance of BSe, MCO monolayers and BSe-MCO (M = Ti, Zr, Hf) van der Waals heterostructures.. <i>RSC Advances</i> , 2021 , 12, 42-52	3.7	2
70	First principles study of electronic and optical properties and photocatalytic performance of GaN-SiS van der Waals heterostructure.. <i>RSC Advances</i> , 2021 , 11, 32996-33003	3.7	4
69	Effects of La and Ce doping on electronic structure and optical properties of janus MoSSe monolayer. <i>Superlattices and Microstructures</i> , 2021 , 151, 106841	2.8	1
68	Stacking effects in van der Waals heterostructures of blueP and Janus XYO (X = Ti, Zr, Hf; Y = S, Se) monolayers.. <i>RSC Advances</i> , 2021 , 11, 12189-12199	3.7	4
67	Two-dimensional blue phosphoreneBAs vdW heterostructure with optical and photocatalytic properties: a first-principles study. <i>RSC Advances</i> , 2021 , 11, 13025-13029	3.7	1
66	First-principles study of the electronic structures and optical and photocatalytic performances of van der Waals heterostructures of SiS, P and SiC monolayers.. <i>RSC Advances</i> , 2021 , 11, 14263-14268	3.7	6
65	Effect of strain on structural and electronic properties, and thermoelectric response of MXY (M=Zr, Hf and Pt; X/Y=S, Se) vdW heterostructures; A first principles study. <i>Journal of Solid State Chemistry</i> , 2021 , 299, 122189	3.3	6
64	Strain engineering of Janus ZrSSe and HfSSe monolayers and ZrSSe/HfSSe van der Waals heterostructure. <i>Chemical Physics Letters</i> , 2021 , 776, 138689	2.5	4
63	Van der Waals heterostructure of Janus transition metal dichalcogenides monolayers (WSSe-WX ₂ (X=S, Se)). <i>Chemical Physics</i> , 2021 , 549, 111252	2.3	2
62	Van der Waal heterostructure based on BY(Y As, P) and MX ₂ (M Mo, W; X S, Se) monolayers. <i>Applied Surface Science</i> , 2021 , 568, 150846	6.7	3
61	CsNaGaBr: a new lead-free and direct band gap halide double perovskite.. <i>RSC Advances</i> , 2020 , 10, 17444-17451	5.13	13
60	Interlayer coupling and electric field controllable Schottky barriers and contact types in graphene/PbI ₂ heterostructures. <i>Physical Review B</i> , 2020 , 101,	3.3	45
59	Effects of electric field and strain engineering on the electronic properties, band alignment and enhanced optical properties of ZnO/Janus ZrSSe heterostructures.. <i>RSC Advances</i> , 2020 , 10, 9824-9832	3.7	9

58	Effects of different surface functionalization on the electronic properties and contact types of graphene/functionalized-GeC van der Waals heterostructures. <i>Physical Chemistry Chemical Physics</i> , 2020 , 22, 7952-7961	3.6	15
57	A first-principles study of electronic structure and photocatalytic performance of GaN-MX (M = Mo, W; X = S, Se) van der Waals heterostructures.. <i>RSC Advances</i> , 2020 , 10, 24683-24690	3.7	9
56	Electronic structure, optoelectronic properties and enhanced photocatalytic response of GaN-GeC van der Waals heterostructures: a first principles study.. <i>RSC Advances</i> , 2020 , 10, 24127-24133	3.7	11
55	Electronic and optoelectronic properties of van der Waals heterostructure based on graphene-like GaN, blue phosphorene, SiC, and ZnO: A first principles study. <i>Journal of Applied Physics</i> , 2020 , 127, 245302	3.5	7
54	Van der Waals heterostructures of SiC and Janus MSSe (M = Mo, W) monolayers: a first principles study.. <i>RSC Advances</i> , 2020 , 10, 25801-25807	3.7	8
53	Electronic structure and optical performance of PbI ₂ /SnSe ₂ heterostructure. <i>Chemical Physics</i> , 2020 , 533, 110736	2.3	2
52	Computational insights into structural, electronic and optical characteristics of GeC/CN van der Waals heterostructures: effects of strain engineering and electric field.. <i>RSC Advances</i> , 2020 , 10, 2967-2974	3.7	7
51	Realization of noble heterobilayers with enhanced optoelectronic properties. <i>Applied Surface Science</i> , 2020 , 505, 144530	6.7	3
50	Graphene/WSeTe van der Waals heterostructure: Controllable electronic properties and Schottky barrier via interlayer coupling and electric field. <i>Applied Surface Science</i> , 2020 , 507, 145036	6.7	92
49	Strain engineering of the electro-optical and photocatalytic properties of single-layered Janus MoSSe: First principles calculations. <i>Optik</i> , 2020 , 224, 165503	2.5	4
48	Interfacial characteristics, Schottky contact, and optical performance of a graphene/Ga ₂ SSe van der Waals heterostructure: Strain engineering and electric field tunability. <i>Physical Review B</i> , 2020 , 102,	3.3	55
47	Electronic structures, and optical and photocatalytic properties of the BPBSe van der Waals heterostructures. <i>New Journal of Chemistry</i> , 2020 , 44, 14964-14969	3.6	5
46	Intriguing electronic structure and photocatalytic performance of blueP-SMSe and blueP-SeMS (M = Mo, W) van der Waals heterostructures.. <i>RSC Advances</i> , 2020 , 10, 38114-38119	3.7	3
45	Optoelectronic and photocatalytic applications of hBP-XMY (M = Mo, W; (X Y) = S, Se, Te) van der Waals heterostructures. <i>Physical Chemistry Chemical Physics</i> , 2020 , 22, 23028-23037	3.6	3
44	Electronic and photocatalytic properties of two-dimensional boron phosphide/SiC van der Waals heterostructure with direct type-II band alignment: a first principles study.. <i>RSC Advances</i> , 2020 , 10, 32027-32033	3.7	3
43	van der Waals heterostructures based on MSSe (M = Mo, W) and graphene-like GaN: enhanced optoelectronic and photocatalytic properties for water splitting. <i>Physical Chemistry Chemical Physics</i> , 2020 , 22, 20704-20711	3.6	11
42	Type-I band alignment of BX-ZnO (X = As, P) van der Waals heterostructures as high-efficiency water splitting photocatalysts: a first-principles study.. <i>RSC Advances</i> , 2020 , 10, 44545-44550	3.7	7
41	Electronic properties and enhanced photocatalytic performance of van der Waals heterostructures of ZnO and Janus transition metal dichalcogenides. <i>Physical Chemistry Chemical Physics</i> , 2020 , 22, 10351-10359	3.6	26

40	Understanding the electronic properties, contact types and optical performances in graphene/InN heterostructure: Role of electric gating. <i>Diamond and Related Materials</i> , 2020 , 106, 107851	3.5	7
39	Tri-layered van der Waals heterostructures based on graphene, gallium selenide and molybdenum selenide. <i>Journal of Applied Physics</i> , 2019 , 125, 225304	2.5	10
38	Strain engineering and electric field tunable electronic properties of Ti ₂ CO ₂ MXene monolayer. <i>Materials Research Express</i> , 2019 , 6, 065910	1.7	4
37	Van der Waals heterostructures of P, BSe, and SiC monolayers. <i>Journal of Applied Physics</i> , 2019 , 125, 094301	2.5	45
36	Electric field tunable electronic properties of P-ZnO and SiC-ZnO van der Waals heterostructures. <i>Computational Materials Science</i> , 2019 , 164, 166-170	3.2	20
35	First-principles study of metal-semiconductor contact between MX ₂ (M = Nb, Pt; X = S, Se) monolayers. <i>Physics Letters, Section A: General, Atomic and Solid State Physics</i> , 2019 , 383, 125867	2.3	2
34	Optoelectronic and solar cell applications of Janus monolayers and their van der Waals heterostructures. <i>Physical Chemistry Chemical Physics</i> , 2019 , 21, 18612-18621	3.6	77
33	Strain and electric field engineering of band alignment in InSe/Ca(OH) ₂ heterostructure. <i>Chemical Physics Letters</i> , 2019 , 732, 136649	2.5	5
32	Intriguing electronic and optical properties of M ₂ CX ₂ (M = Mo, W; X = O, F) MXenes and their van der Waals heterostructures. <i>Chemical Physics Letters</i> , 2019 , 731, 136614	2.5	2
31	Van der Waals heterostructures of blue phosphorene and scandium-based MXenes monolayers. <i>Journal of Applied Physics</i> , 2019 , 126, 143101	2.5	6
30	Rashba spin splitting and photocatalytic properties of GeCM ₂ SSe (M=Mo, W) van der Waals heterostructures. <i>Physical Review B</i> , 2019 , 100,	3.3	92
29	Strain and electric field tunable electronic properties of type-II band alignment in van der Waals GaSe/MoSe ₂ heterostructure. <i>Chemical Physics</i> , 2019 , 521, 92-99	2.3	15
28	Band alignment and optical features in Janus-MoSeTe/X(OH) (X = Ca, Mg) van der Waals heterostructures. <i>Physical Chemistry Chemical Physics</i> , 2019 , 21, 25849-25858	3.6	36
27	Tailoring the structural and electronic properties of an SnSe/MoS van der Waals heterostructure with an electric field and the insertion of a graphene sheet. <i>Physical Chemistry Chemical Physics</i> , 2019 , 21, 22140-22148	3.6	32
26	Vertical strain and electric field tunable electronic properties of type-II band alignment C ₂ N/InSe van der Waals heterostructure. <i>Chemical Physics Letters</i> , 2019 , 716, 155-161	2.5	30
25	Theoretical investigation of electronic structure and thermoelectric properties of MX ₂ (M=Zr, Hf; X=S, Se) van der Waals heterostructures. <i>Journal of Physics and Chemistry of Solids</i> , 2019 , 126, 304-309	3.9	19
24	Van der Waals graphene/g-GaSe heterostructure: Tuning the electronic properties and Schottky barrier by interlayer coupling, biaxial strain, and electric gating. <i>Journal of Alloys and Compounds</i> , 2018 , 750, 765-773	5.7	45
23	Intriguing electronic structures and optical properties of two-dimensional van der Waals heterostructures of Zr ₂ CT ₂ (T = O, F) with MoSe ₂ and WSe ₂ . <i>Journal of Materials Chemistry C</i> , 2018 , 6, 2830-2839	7.1	43

22	First principles study of the electronic properties and Schottky barrier in vertically stacked graphene on the Janus MoSeS under electric field. <i>Computational Materials Science</i> , 2018 , 153, 438-444	3.2	45
21	Structural and electronic properties of a van der Waals heterostructure based on silicene and gallium selenide: effect of strain and electric field. <i>Physical Chemistry Chemical Physics</i> , 2018 , 20, 27856-27864	3.6	54
20	Layered graphene/GaS van der Waals heterostructure: Controlling the electronic properties and Schottky barrier by vertical strain. <i>Applied Physics Letters</i> , 2018 , 113, 171605	3.4	141
19	Electronic structure, optical and photocatalytic performance of SiC-MX (M = Mo, W and X = S, Se) van der Waals heterostructures. <i>Physical Chemistry Chemical Physics</i> , 2018 , 20, 24168-24175	3.6	60
18	Influence of strain on specific features of MoX ₂ (X = S, Se, Te) monolayers. <i>Physica B: Condensed Matter</i> , 2018 , 545, 113-118	2.8	11
17	Strain engineering of electronic structures and photocatalytic responses of MXenes functionalized by oxygen. <i>Physical Chemistry Chemical Physics</i> , 2017 , 19, 14738-14744	3.6	40
16	Thermoelectric properties of the misfit cobaltate Ca ₃ Co ₄ O ₉ . <i>Applied Physics Letters</i> , 2017 , 110, 233505	3.4	6
15	Theoretical exploration of the potential applications of Sc-based MXenes. <i>Physical Chemistry Chemical Physics</i> , 2017 , 19, 32253-32261	3.6	23
14	Materials properties of out-of-plane heterostructures of MoS ₂ -WSe ₂ and WS ₂ -MoSe ₂ . <i>Applied Physics Letters</i> , 2016 , 108, 063105	3.4	60
13	Structural, elastic, thermal and electronic properties of M ₂ X (M = Sr, Ba and X = Si, Ge, Sn) compounds in anti-fluorite structure: first principle calculations. <i>Indian Journal of Physics</i> , 2015 , 89, 369-375	1.4	7
12	Heterostructures of transition metal dichalcogenides. <i>Physical Review B</i> , 2015 , 92,	3.3	146
11	Strain engineering of WS ₂ , WSe ₂ , and WTe ₂ . <i>RSC Advances</i> , 2014 , 4, 34561	3.7	216
10	Major enhancement of the thermoelectric performance in Pr/Nb-doped SrTiO ₃ under strain. <i>Applied Physics Letters</i> , 2013 , 103, 031907	3.4	23
9	ELECTRONIC BAND STRUCTURE, OPTICAL, THERMAL AND BONDING PROPERTIES OF XMg ₂ O ₄ (X = Si, Ge) SPINEL COMPOUNDS. <i>International Journal of Modern Physics B</i> , 2013 , 27, 1350082	1.1	8
8	STRUCTURAL, ELASTIC, ELECTRONIC, CHEMICAL BONDING AND OPTICAL PROPERTIES OF M ₂ Se (M = Li, Na, K, Rb) THROUGH FIRST PRINCIPLE STUDY. <i>International Journal of Modern Physics B</i> , 2013 , 27, 1350170	1.1	8
7	Molecular distortion and charge transfer effects in ZnPc/Cu(111). <i>Scientific Reports</i> , 2013 , 3,	4.9	17
6	Electronic structure of cubic perovskite SnTaO ₃ . <i>Intermetallics</i> , 2012 , 31, 287-291	3.5	41
5	Theoretical investigation of half-metallicity in Co/Ni substituted AlN. <i>International Journal of Quantum Chemistry</i> , 2012 , 112, 882-888	2.1	12

- 4 Robust half-metallicity of AlCoN and AlNiN. *International Journal of Quantum Chemistry*, **2012**, 112, 2668-2674
- 3 Ab initio study of the bandgap engineering of Al_{1-x}GaxN for optoelectronic applications. *Journal of Applied Physics*, **2011**, 109, 023109 2.5 129
- 2 Cr-Doped III^V Nitrides: Potential Candidates for Spintronics. *Journal of Electronic Materials*, **2011**, 40, 1428-1436 1.9 38
- 1 Investigation of structural and optoelectronic properties of BaThO₃. *Optical Materials*, **2011**, 33, 553-557 3.3 87